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## Anthryl-Substituted Trialkyldisilene Showing Distinct Intramolecular Charge-Transfer Transition

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Although many stable disilenes hitherto reported<sup>1</sup> have organic  $\pi$ -electron systems as bulky sterically protecting substituents, very few studies have been directed toward understanding the characteristics of the electronic communication including conjugation and intramolecular charge transfer (ICT) interaction between a Si=Si double bond ( $\pi$ Si) and a carbon  $\pi$ -electron system ( $\pi$ C).<sup>2</sup> All known disilenes bound to  $\pi C$  systems have multiple  $\pi Si - \pi C$  interactions and, hence, are not suitable for defining the nature of a single  $\pi Si - \pi C$  interaction.<sup>2</sup> We would like to report the synthesis and properties of a series of trialkyldisilenes with single polycyclic aromatic substituents 1-3.<sup>3</sup> These disilenes allowed elucidation of the unprecedented ICT interaction between  $\pi$ Si and  $\pi$ C systems, while no appreciable  $\pi Si - \pi C$  conjugation is expected because of their mutually perpendicular arrangement. Anthryl-substituted disilene **3** having a low-lying  $\pi^*(aryl)$  LUMO showed a distinct ICT absorption band due to the charge transfer from a  $\pi$ Si donor to a  $\pi C$  acceptor.



To synthesize disilenes 1–3, new disilenide 4 was prepared by reduction of trichlorodisilane 6, which was obtained from isolable dialkylsilylene 5<sup>4</sup> and *t*-BuSiCl<sub>3</sub>,<sup>5</sup> with excess KC<sub>8</sub> in THF (Scheme 1).<sup>6,7</sup> While stable disilenides have been extensively investigated by Scheschkewitz<sup>8</sup> and Sekiguchi et al.,<sup>9</sup> 4 is unique in that it is a trialkyldisilenide without any  $\pi$  substituents.

## Scheme 1



Disilenes 1-3 were synthesized by reactions of 4 with the corresponding aryl bromides.<sup>6</sup> Recrystallization from diethyl ether at -30 °C gave air-sensitive colored crystals of disilenes: 1-naph-thyldisilene 1 (10%, yellow), 9-phenanthryldisilene 2 (20%, yellow), and 9-anthryldisilene 3 (41%, blue-purple).<sup>10</sup>

Molecular structures of disilenes 1-3 determined by X-ray analysis are shown in Figure 1.<sup>6</sup> All disilenes have a *trans*-bent geometry around the Si=Si double bond with bent angles<sup>11</sup> of 23.8° and 12.2°, 26.7° and 12.9°, and 11.4° and 6.9° around Si1 and Si2 atoms of **1**, **2**, and **3**, respectively. The Si=Si bond lengths [2.1943(14), 2.209(2), and 2.1754(12) Å for 1–3] are in the region of those for typical acyclic disilenes.<sup>1</sup> It should be noted that disilene  $\pi$  ( $\pi$ Si) and aromatic  $\pi$  ( $\pi$ C) systems are almost perpendicular to each other with a dihedral angle  $\delta^{11}$  of 83°, 80°, and 88° for 1, 2, and 3.



**Figure 1.** Molecular structures of 1 (left), 2 (middle), and 3 (right). Thermal ellipsoids are shown at the 50% probability level. Hydrogen atoms are omitted for clarity.

Disilenes 1 and 2 in 3-methylpentane show similar three absorption bands (bands I-III) in the UV-vis region as typically shown for 1 in Figure 2a.<sup>12</sup> Band I having fine structures is observed at 287 and 304 nm for 1 and 2, respectively, and assignable to the  ${}^{1}L_{a}$  band of the corresponding  $\pi C$  systems because the reported  ${}^{1}L_{a}$  band maxima of 1-(pentamethyldisilanyl)naphthalene and 9-(pentamethyldisilanyl)phenanthrene are 287 and 302 nm.<sup>13</sup> The other two major bands of 1 and 2 (bands II and III) are very similar to each other, and hence, these bands are assigned to the transition originating from the common disilene moiety;  $\lambda_{max}/nm$  342 and 376 for 1 and 343 and 378 for 2.14 An apparent spectral feature of anthryldisilene 3 is very different from those of 1 and 2 as shown in Figure 2b, but the intense structured band between 320 and 450 nm with an  $\varepsilon$  of 19.7  $\times$  10<sup>3</sup> is regarded as band I overlapped with bands II and III, because the  ${}^{1}L_{a}$  band of 9-(pentamethyldisilany-1)anthracene appears at 373 nm with an  $\varepsilon$  of 8.42  $\times$  10<sup>3</sup>.<sup>13</sup> All these spectral features are in good accord with the picture that the  $\pi$ Si and  $\pi C$  systems are independent of each other and there is no significant conjugation between the two  $\pi$  systems, as expected by the mutually perpendicular arrangement of the two  $\pi$  systems.

A noticeable spectral feature of **3** is the presence of a weak but distinct absorption band at 525 nm ( $\varepsilon$  420) in 3-methylpentane (band IV), which red-shifts to 535 nm ( $\varepsilon$  480) in more polar 1,2-dichlorobenzene,<sup>15</sup> suggesting the ICT nature of this band.

To elucidate the nature of the absorption bands of 1-3, DFT calculations at the B3LYP/6-311G(d) level<sup>16</sup> are carried out for model compounds 1'-3', where SiMe<sub>3</sub> groups in 1-3 are replaced by SiH<sub>3</sub> groups. The molecular structures of disilenes 1-3

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determined by X-ray crystallography are reproduced well in optimized structures of 1'-3'. The almost perpendicular geometry between the Si=Si bond and aromatic  $\pi$  plane in 1'-3' ( $\delta$  82°, 81°, and 83° for 1', 2', and 3') supports compounds 1-3 having similar perpendicular geometry even in solution. Frontier Kohn-Sham orbitals of 1'-3' are almost pure  $\pi$  and  $\pi^*$  orbitals of disilene and aryl moieties, and their energy levels are almost the same as those of the component  $\pi$ Si and  $\pi$ C systems,<sup>16</sup> indicating no significant conjugative interaction between the two  $\pi$  systems (Figure 3). The calculated absorption maxima and oscillator strengths of 1'-3' using the TD-DFT method show good qualitative agreement with those of 1-3: the band positions and relative intensities for 1' and 3' are shown using vertical bars in Figure 2.



Figure 2. UV-vis spectra of (a) 1 and (b) 3 in 3-methylpentane at 298 K superimposed by the calculated band positions of 1' and 3'. Selected theoretical transitions: a:  $\pi(aryl) \rightarrow \pi^*(aryl)$ , b:  $\pi(Si=Si) \rightarrow \sigma^*(ring Si=C)$ , c:  $\pi(Si=Si) \rightarrow \pi^*(Si=Si)$ , d:  $\pi(Si=Si) \rightarrow \pi^*(aryl)$ .



Figure 3. Orbital energy diagram of aryldisilenes 1'-3' calculated at the B3LYP/6-311++G(d,p)//B3LYP/6-311G(d) level.

Judging from the comparison between experimental and theoretical UV-vis spectra, bands I, II, and III of disilenes 1-3 are assignable to transitions a  $[\pi(aryl) \rightarrow \pi^*(aryl)]$ , b  $[\pi(Si=Si) \rightarrow \sigma^*(ring)]$ Si-C)], and c  $[\pi(Si=Si) \rightarrow \pi^*(Si=Si)]$ . Theoretical calculations confirm that the broad 320-450 nm band of 3 is due to the overlap of bands a, b, and c. The weak absorption at 525 nm of 3 (band IV) is assigned as an ICT transition from  $\pi(Si=Si)$  to  $\pi^*(aryl)$ orbitals (transition d). Because similar  $\pi Si \rightarrow \pi^*C$  ICT transition bands are predicted at 444 and 444 nm for 1' and 2', the broad tails of band III of 1 and 2 may be assigned to the ICT absorption bands. The absorption spectra of 1-3 suggests that a  $\pi C$  system having a lower-lying  $\pi^*$  LUMO such as anthracene and longer acenes is indispensable for a distinct longer-wavelength ICT band.<sup>17</sup>

The present study offers a guideline to designing unique materials showing effective ICT interaction between a  $\pi$ Si donor and a  $\pi$ C acceptor.18

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Supporting Information Available: Experimental details for 1-4, details for the calculations of 1'-3' and related compounds, and X-ray crystallographic data of 1-4 in CIF format. This material is available free of charge via the Internet at http://pubs.acs.org.

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- Information.
- (7)In the solid state, disilenide 4 adopts a dimeric structure with a fourmembered ring made of  $Si(sp^2)-K-Si(sp^2)-K$  atoms, while disilenides reported by Scheschkewitz<sup>8</sup> and Sekiguchi et al.<sup>9</sup> are monomeric.
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- (10) The reaction of 4 with bromobenzene gave a complex mixture.
- (11) Bent angle is defined as the angle between the axis through the Si=Si bond and R—Si(sp<sup>2</sup>)—R plane, and dihedral angle  $\delta$  is defined as the angle between the two axes that bisect Si(sp<sup>2</sup>)-Si(sp<sup>2</sup>)-C(t-Bu) and  $C(sp^2)-C(ipso)-C(sp^2)$  angles as viewed along the  $Si(sp^2)-C(aryl)$  bond axis
- (12) See Supporting Information for details of UV-vis spectrum of 2.
- (13) The  $\lambda_{\text{max}}$  ( $\varepsilon$ ) of the <sup>1</sup>L<sub>a</sub> of 1-naphthyl-, 9-phenanthryl-, and 9-anthryl-Substituted pentamethyldisilanes are reported to be 287 nm  $(9.94 \times 10^3)$ , 302 nm  $(1.62 \times 10^4)$ , and 373 nm  $(8.42 \times 10^3)$ , respectively. Shizuka, H.; Sato, Y.; Ueki, Y.; Ishikawa, M.; Kumada, M. J. Chem. Soc., Faraday Trans. 1 1984, 80, 341.
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- (18) Preliminarily, when band I of **3** was excited in hexane, emission from anthryl  $\pi\pi^*$  state was observed at 415 nm with a lower quantum yield (0.14) than that for 9-anthrylpentamethyldisilane (0.73).<sup>13</sup> Excitation of the ICT band showed no emission.

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